



DMN3066LQ

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
	67mΩ @ Vgs = 4.5V	3.6A
30V	70mΩ @ V _{GS} = 4.0V	3.5A
	98mΩ @ Vgs = 2.5V	3.0A

Description

This new generation MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

Load Switch

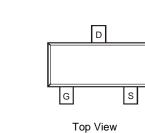
Features

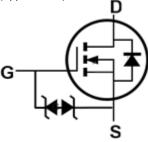
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN3066LQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)





Pin-Out

Equivalent Circuit

Ordering Information (Note 4)

ESD Protected Gate

Part Number	Case	Packaging
DMN3066LQ-7	SOT23	3,000/Tape & Reel
DMN3066LQ-13	SOT23	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

BF5	ΜY

SOT23

Top View

 $\frac{BF5}{YM} = \text{Product Type Marking Code}$ $\frac{YM}{Y} = \text{Date Code Marking}$ $\frac{Y}{Y} = \text{Year (ex: I = 2021)}$ $M = \text{Month (ex: 9 = \text{September})}$

Date Code Key

Notes:

Date Code Key												
Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	I	J	K	L	M	N	0	Р	R	S	Т	U
-												
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		Vdss	30	V	
Gate-Source Voltage	Vgss	±12	V		
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$ State $T_A = +25^{\circ}C$ $T_A = +85^{\circ}C$			lD	3.6 2.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)		I _{DM}	21	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.81	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	154	°C/W
Total Power Dissipation (Note 6)		Po	1.33	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	94	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

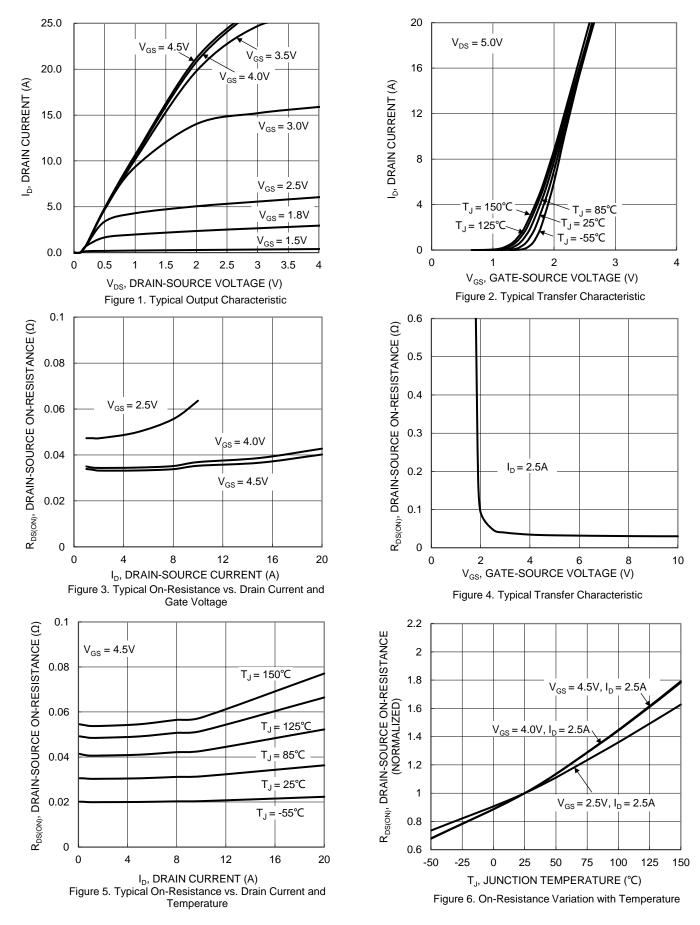
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						-
Drain-Source Breakdown Voltage	BVDSS	30	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}		—	1.0	μA	$V_{DS} = 30V, V_{GS} = 0V$
Gate-Source Leakage	lgss		—	±10	μA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5	—	1.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
			29	67		V _{GS} = 4.5V, I _D = 2.5A
Static Drain-Source On-Resistance	RDS(ON)	—	31	70	mΩ	$V_{GS} = 4.0V, I_D = 2.5A$
			43	98		V _{GS} = 2.5V, I _D = 2.5A
Diode Forward Voltage	Vsd		0.7	1.2	V	V _{GS} = 0V, I _S = 0.6A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	353	—	pF	
Output Capacitance	Coss		60	—	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	42	—	pF	
Gate Resistance	Rg		4.7	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg	_	4.1	—	nC	
Gate-Source Charge	Qgs	—	0.6	—	nC	VGS = 4.5V, VDS = 15V, ID = 2.5A
Gate-Drain Charge	Q _{gd}	—	1.2	—	nC	10 = 2.5A
Turn-On Delay Time	td(on)	_	5.7	_	ns	
Turn-On Rise Time	tR	_	19	_	ns	Vdd = 15V, Id = 1.25A, Vgen = 4.5V.
Turn-Off Delay Time	tD(OFF)		22		ns	$R_{GEN} = 4.5V,$ RGEN = 10 Ω
Turn-Off Fall Time	tF		11	_	ns	7

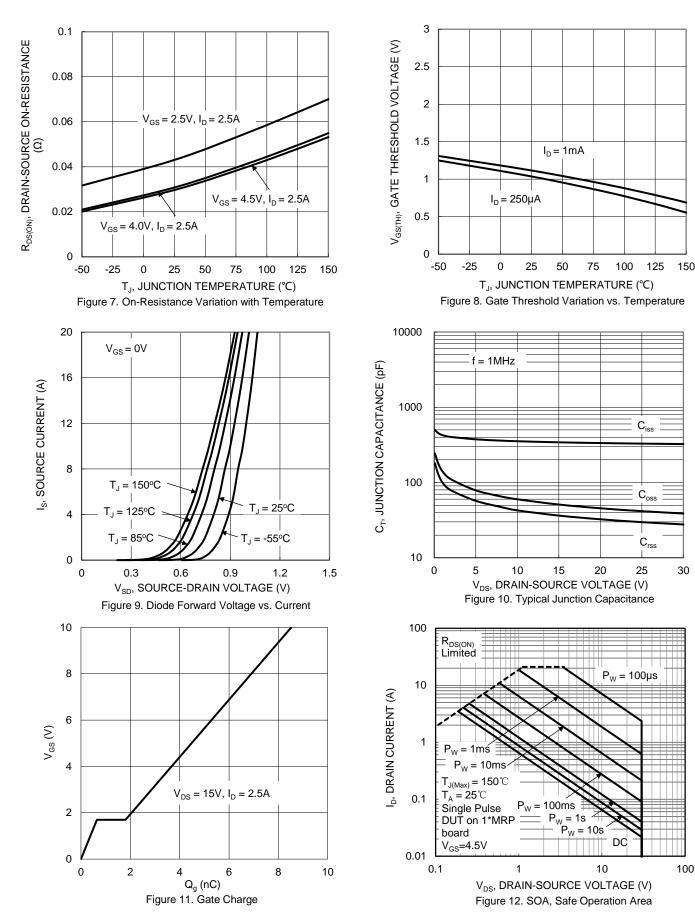
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing



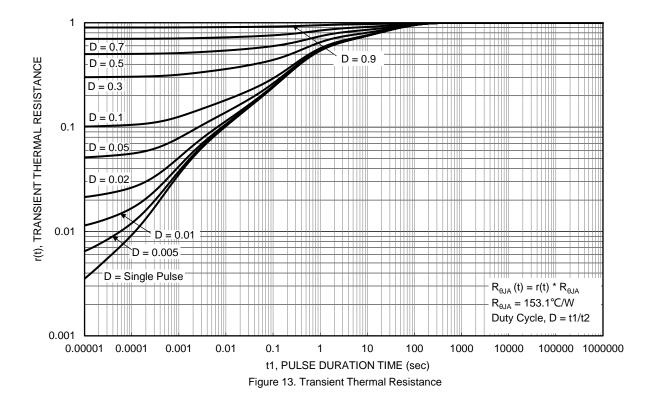






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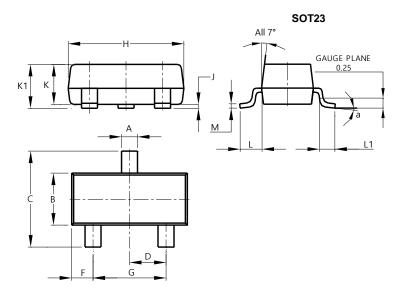






Package Outline Dimensions

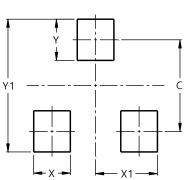
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Н	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а	0°	8°	
All	Dimens	ions in	mm

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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